

Voltage Regulator -Adjustable Output, **Negative**

1.5 A

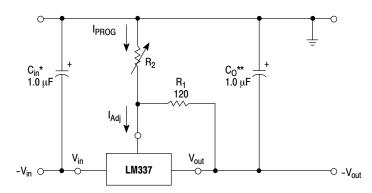
LM337

The LM337 is an adjustable 3-terminal negative voltage regulator capable of supplying in excess of 1.5 A over an output voltage range of -1.2 V to -37 V. This voltage regulator is exceptionally easy to use and requires only two external resistors to set the output voltage. Further, it employs internal current limiting, thermal shutdown and safe area compensation, making it essentially blow-out proof.

The LM337 serves a wide variety of applications including local, on card regulation. This device can also be used to make a programmable output regulator, or by connecting a fixed resistor between the adjustment and output, the LM337 can be used as a precision current regulator.

Features

- Output Current in Excess of 1.5 A
- Output Adjustable between -1.2 V and -37 V
- Internal Thermal Overload Protection
- Internal Short Circuit Current Limiting Constant with Temperature
- Output Transistor Safe-Area Compensation
- Floating Operation for High Voltage Applications
- Eliminates Stocking many Fixed Voltages
- Available in Surface Mount D²PAK and Standard 3-Lead Transistor Package
- These Devices are Pb-Free and are RoHS Compliant



^{*}C_{in} is required if regulator is located more than 4 inches from power supply filter. A 1.0 μF solid tantalum or 10 μF aluminum electrolytic is recommended.

$$V_{out} = -1.25 V \left(1 + \frac{R_2}{R_1} \right)$$

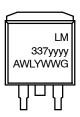
Figure 1. Standard Application

THREE-TERMINAL ADJUSTABLE NEGATIVE **VOLTAGE REGULATOR**

MARKING DIAGRAMS



D²PAK **D2T SUFFIX CASE 936**



Heatsink surface (shown as terminal 4 in case outline drawing) is connected to Pin 2.

> Pin 1. Adjust 2. V_{in} 3. V_{out}



TO-220AB **T SUFFIX** CASE 221AB

Heatsink surface connected to Pin 2.



= BT. T

= BD2T, D2T

Assembly Location Wafer Lot

= Year = Work Week = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

1

^{**} C_0 is necessary for stability. A 1.0 μF solid tantalum or 10 μF aluminum electrolytic is recommended.

MAXIMUM RATINGS ($T_A = +25^{\circ}C$, unless otherwise noted)

Rating	Symbol	Value	Unit
Input-Output Voltage Differential	V_I – V_O	40	Vdc
Power Dissipation Case 221A T _A = +25°C Thermal Resistance, Junction-to-Ambient Thermal Resistance, Junction-to-Case Case 936 (D ² PAK) T _A = +25°C Thermal Resistance, Junction-to-Ambient Thermal Resistance, Junction-to-Case		Internally Limited 65 5.0 Internally Limited 70 5.0	W °C/W °C/W °C/W °C/W
Operating Junction Temperature Range	TJ	-40 to +125	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ELECTRICAL CHARACTERISTICS (|V_{I-}V_O| = 5.0 V; I_O = 0.5 A for T package; T_{.J} = T_{low} to T_{high} [Note 1]; I_{max} and P_{max} [Note 2].)

Characteristics	Figure	Symbol	Min	Тур	Max	Unit
Line Regulation (Note 3), $T_A = +25^{\circ}C$, $3.0 \text{ V} \le V_I - V_O \le 40 \text{ V}$	1	Reg _{line}		0.01	0.04	%/V
Load Regulation (Note 3), T_A = +25°C, 10 mA \leq $I_O \leq$ I_{max} $ V_O \leq$ 5.0 V $ V_O \geq$ 5.0 V	2	Reg _{load}	- -	15 0.3	50 1.0	mV % V _O
Thermal Regulation, $T_A = +25^{\circ}C$ (Note 5), 10 ms Pulse		Reg _{therm}	-	0.003	0.04	% V _O /W
Adjustment Pin Current	3	I_{Adj}	-	65	100	μΑ
Adjustment Pin Current Change, $2.5 \text{ V} \le V_I - V_O \le 40 \text{ V}$, $10 \text{ mA} \le I_L \le I_{max}, \ P_D \le P_{max}, \ T_A = +25^{\circ}\text{C}$	1, 2	ΔI_{Adj}	-	2.0	5.0	μΑ
Reference Voltage, $T_A = +25^{\circ}C$, $3.0 \text{ V} \le V_I - V_O \le 40 \text{ V}$, $10 \text{ mA} \le I_O \le I_{max}$, $P_D \le P_{max}$, $T_J = T_{low}$ to T_{high}	3	V _{ref}	-1.213 -1.20	-1.250 -1.25	-1.287 -1.30	V
Line Regulation (Note 3), 3.0 V \leq V _I -V _O \leq 40 V	1	Reg _{line}	-	0.02	0.07	%/V
Load Regulation (Note 3), 10 mA \leq I _O \leq I _{max} $ V_O \leq 5.0 \text{ V}$ $ V_O \geq 5.0 \text{ V}$	2	Reg _{load}	- -	20 0.3	70 1.5	mV % V _O
Temperature Stability $(T_{low} \le T_J \le T_{high})$	3	T _S	-	0.6	_	% V _O
Minimum Load Current to Maintain Regulation	3	I _{Lmin}	_ _	1.5 2.5	6.0 10	mA
$\begin{aligned} \text{Maximum Output Current} \\ V_I - V_O &\leq 15 \text{ V}, \text{ P}_D \leq \text{P}_{max}, \text{ T Package} \\ V_I - V_O &\leq 40 \text{ V}, \text{ P}_D \leq \text{P}_{max}, \text{ T}_J = +25^{\circ}\text{C}, \text{ T Package} \end{aligned}$	3	I _{max}	- -	1.5 0.15	2.2 0.4	А
RMS Noise, % of V_O , T_A = +25°C, 10 Hz \leq f \leq 10 kHz		N		0.003	_	% Vo
Ripple Rejection, V_O = -10 V, f = 120 Hz (Note 4) Without C_{Adj} C_{Adj} = 10 μF	4	RR	- 66	60 77	- -	dB
Long-Term Stability, T _J = T _{high} (Note 6), T _A = +25°C for Endpoint Measurements	3	S	-	0.3	1.0	%/1.0 k Hrs.
Thermal Resistance, Junction-to-Case, T Package		$R_{ heta JC}$	-	4.0	-	°C/W

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics for the listed test conditions.

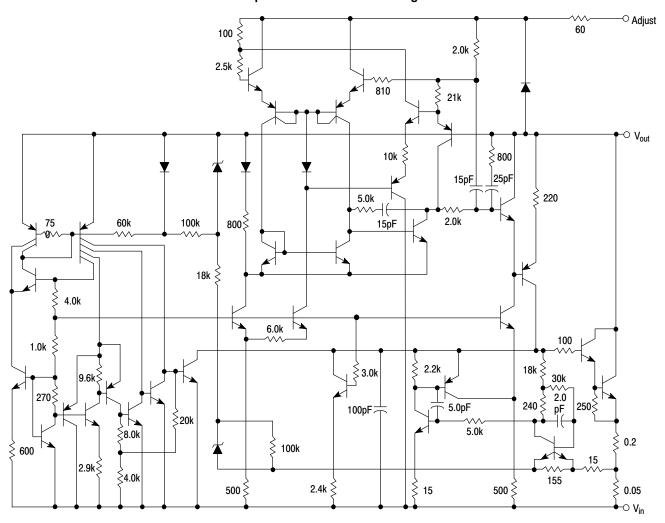
1. T_{low} to T_{high} = 0° to +125°C, for LM337T, D2T. T_{low} to T_{high} = -40° to +125°C, for LM337BT, BD2T.

2. I_{max} = 1.5 Å, P_{max} = 20 W

3. Load and line regulation are specified at constant junction temperature. Change in V_O because of heating effects is covered under the

- Thermal Regulation specification. Pulse testing with a low duty cycle is used.
- 4. C_{Adi}, when used, is connected between the adjustment pin and ground.
- 5. Power dissipation within an IC voltage regulator produces a temperature gradient on the die, affecting individual IC components on the die. These effects can be minimized by proper integrated circuit design and layout techniques. Thermal Regulation is the effect of these temperature gradients on the output voltage and is expressed in percentage of output change per watt of power change in a specified time.
- 6. Since Long Term Stability cannot be measured on each device before shipment, this specification is an engineering estimate of average stability from lot to lot.

Representative Schematic Diagram



This device contains 39 active transistors.

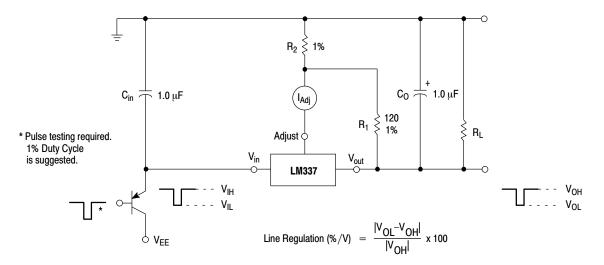


Figure 1. Line Regulation and $\Delta I_{\mbox{Adi}}/\mbox{Line}$ Test Circuit

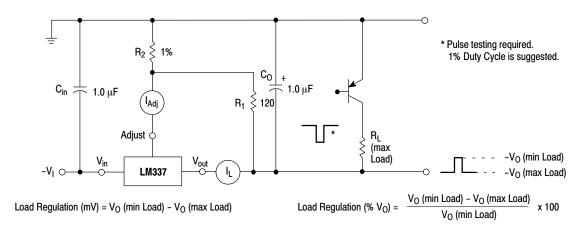


Figure 2. Load Regulation and $\Delta I_{\mbox{\scriptsize Adj}}/\mbox{\scriptsize Load}$ Test Circuit

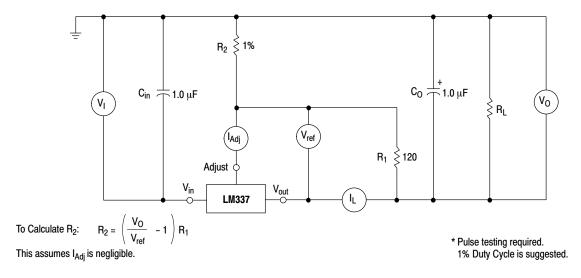


Figure 3. Standard Test Circuit

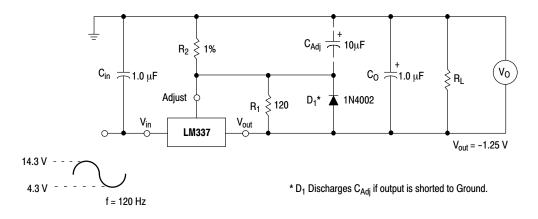


Figure 4. Ripple Rejection Test Circuit

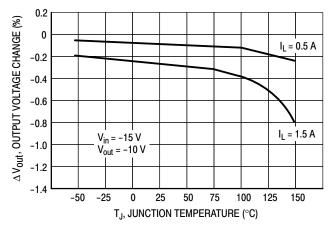


Figure 5. Load Regulation

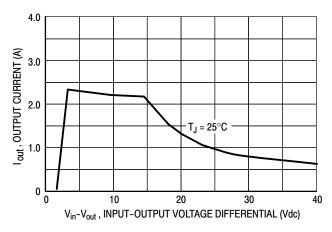


Figure 6. Current Limit

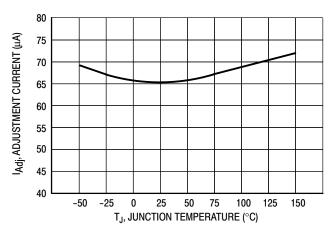


Figure 7. Adjustment Pin Current

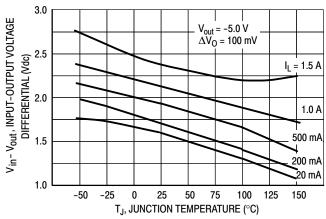


Figure 8. Dropout Voltage

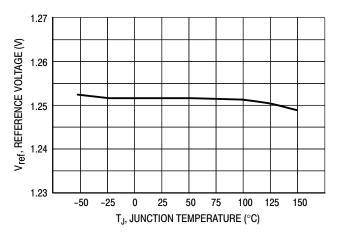


Figure 9. Temperature Stability

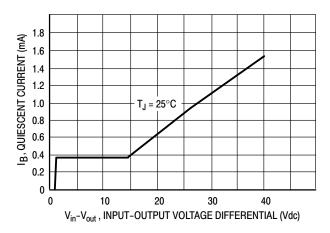
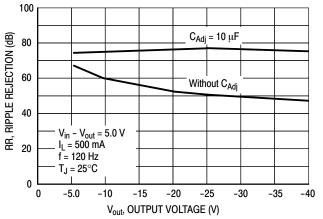


Figure 10. Minimum Operating Current



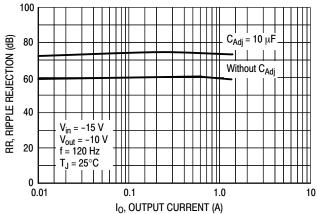
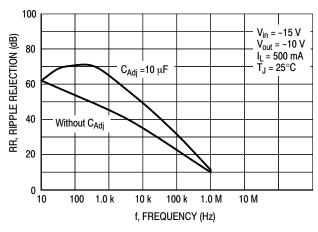


Figure 11. Ripple Rejection versus Output Voltage

Figure 12. Ripple Rejection versus Output Current



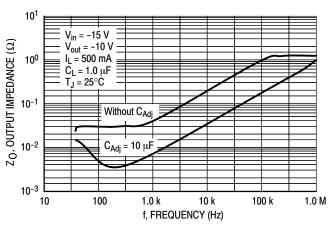
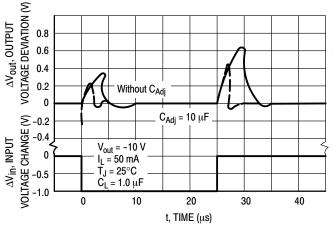


Figure 13. Ripple Rejection versus Frequency

Figure 14. Output Impedance



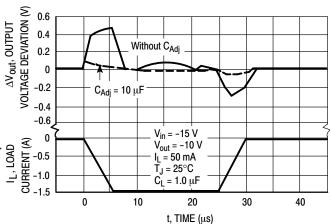


Figure 15. Line Transient Response

Figure 16. Load Transient Response

APPLICATIONS INFORMATION

Basic Circuit Operation

The LM337 is a 3-terminal floating regulator. In operation, the LM337 develops and maintains a nominal -1.25 V reference (V_{ref}) between its output and adjustment terminals. This reference voltage is converted to a programming current (I_{PROG}) by R_1 (see Figure 17), and this constant current flows through R_2 from ground.

The regulated output voltage is given by:

$${\rm V}_{out} \ = \ {\rm V}_{ref} \left({\rm 1} \, + \frac{{\rm R}_2}{{\rm R}_1} \right) \ + \ {\rm I}_{Adj} \, {\rm R}_2$$

Since the current into the adjustment terminal (I_{Adj}) represents an error term in the equation, the LM337 was designed to control I_{Adj} to less than 100 μA and keep it constant. To do this, all quiescent operating current is returned to the output terminal. This imposes the requirement for a minimum load current. If the load current is less than this minimum, the output voltage will rise.

Since the LM337 is a floating regulator, it is only the voltage differential across the circuit which is important to performance, and operation at high voltages with respect to ground is possible.

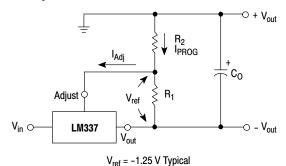


Figure 17. Basic Circuit Configuration

Load Regulation

The LM337 is capable of providing extremely good load regulation, but a few precautions are needed to obtain maximum performance. For best performance, the programming resistor (R_1) should be connected as close to the regulator as possible to minimize line drops which effectively appear in series with the reference, thereby degrading regulation. The ground end of R_2 can be returned near the load ground to provide remote ground sensing and improve load regulation.

External Capacitors

A 1.0 μF tantalum input bypass capacitor (C_{in}) is recommended to reduce the sensitivity to input line impedance.

The adjustment terminal may be bypassed to ground to improve ripple rejection. This capacitor (C_{Adj}) prevents ripple from being amplified as the output voltage is increased. A 10 μF capacitor should improve ripple rejection about 15 dB at 120 Hz in a 10 V application.

An output capacitance (C_O) in the form of a 1.0 μF tantalum or 10 μF aluminum electrolytic capacitor is required for stability. Using the classical tantalum or aluminum electrolytic capacitor types with non-reduced ESR (Equivalent Series Resistance) value is necessary. Low-ESR or similar capacitor types with reduced ESR value and ceramic capacitors can cause instability or continuous oscillations in the application.

Protection Diodes

When external capacitors are used with any IC regulator it is sometimes necessary to add protection diodes to prevent the capacitors from discharging through low current points into the regulator.

Figure 18 shows the LM337 with the recommended protection diodes for output voltages in excess of -25~V or high capacitance values ($C_O > 25~\mu F,\, C_{Adj} > 10~\mu F$). Diode D_1 prevents C_O from discharging thru the IC during an input short circuit. Diode D_2 protects against capacitor C_{Adj} discharging through the IC during an output short circuit. The combination of diodes D_1 and D_2 prevents C_{Adj} from the discharging through the IC during an input short circuit.

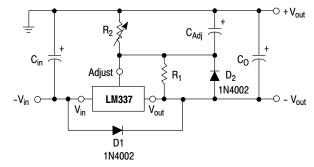


Figure 18. Voltage Regulator with Protection Diodes

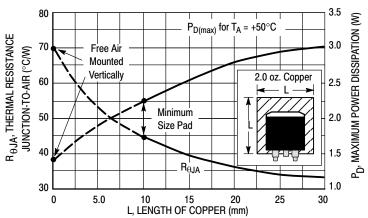


Figure 19. D²PAK Thermal Resistance and Maximum Power Dissipation versus P.C.B. Copper Length

ORDERING INFORMATION

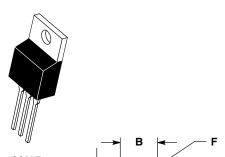
Device	Operating Temperature Range	Package	Shipping [†]
LM337BD2TR4G	$T_{J} = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	D ² PAK (Pb-Free)	800 / Tape & Reel
LM337BTG		TO-220AB (Pb-Free)	50 Units / Rail
LM337D2TR4G	T _J = 0° to +125°C	D ² PAK (Pb-Free)	800 / Tape & Reel
LM337TG		TO-220AB (Pb-Free)	50 Units / Rail

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

ON Semiconductor®





TO-220, SINGLE GAUGE CASE 221AB-01 **ISSUE A**

DATE 16 NOV 2010

- NOTES:

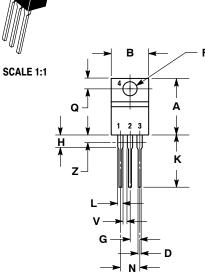
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

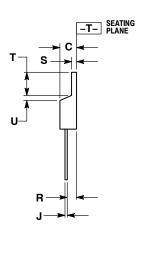
 2. CONTROLLING DIMENSION: INCHES.

 3. DIMENSION 2 DEFINES A ZONE WHERE ALL BODY AND LEAD INREGULARTIES ARE ALLOWED.

 4. PRODUCT SHIPPED PRIOR TO 2008 HAD DIMENSIONS S = 0.045 0.055 INCHES (1.143 1.397 MM)

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.020	0.024	0.508	0.61
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04





STYLE 1:		STYLE 2:		STYLE 3:	
PIN 1.	BASE	PIN 1.	BASE	PIN 1.	CATHODE
2.	COLLECTOR	2.	EMITTER	2.	ANODE
3.	EMITTER	3.	COLLECTOR	3.	GATE
4.	COLLECTOR	4.	EMITTER	4.	ANODE
STYLE 5:		STYLE 6:		STYLE 7:	
PIN 1.	GATE	PIN 1.	ANODE	PIN 1.	CATHODE
2.	DRAIN	2.	CATHODE	2.	ANODE
3.	SOURCE	3.	ANODE	3.	CATHODE
4.	DRAIN	4.	CATHODE	4.	ANODE
STYLE 9:		STYLE 10:		STYLE 11:	
PIN 1.	GATE	PIN 1.	GATE	PIN 1.	DRAIN
2.	COLLECTOR	2.	SOURCE	2.	SOURCE
3.	EMITTER	3.	DRAIN	3.	GATE
4.	COLLECTOR	4.	SOURCE	4.	SOURCE

3.	MAIN TERMINAL 1 MAIN TERMINAL 2 GATE MAIN TERMINAL 2
2. 3.	CATHODE ANODE EXTERNAL TRIP/DELAY ANODE

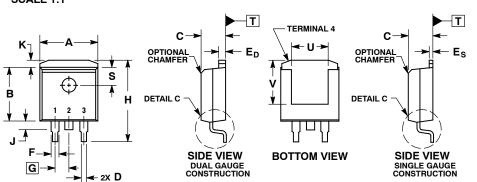
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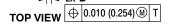
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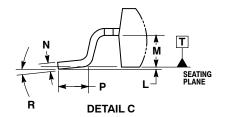


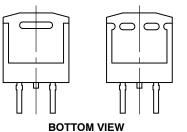
D²PAK CASE 936-03 ISSUE E

DATE 29 SEP 2015







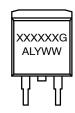


OPTIONAL CONSTRUCTIONS

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCHES. TAB CONTOUR OPTIONAL WITHIN DIMENSIONS
- A AND K.
 DIMENSIONS U AND V ESTABLISH A MINIMUM
- MOUNTING SURFACE FOR TERMINAL 4.
 DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH OR GATE PROTRUSIONS. MOLD FLASH AND GATE PROTRUSIONS NOT TO EXCEED 0.025 (0.635) MAXIMUM.
- SINGLE GAUGE DESIGN WILL BE SHIPPED AF-TER FPCN EXPIRATION IN OCTOBER 2011.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.386	0.403	9.804	10.236
В	0.356	0.368	9.042	9.347
С	0.170	0.180	4.318	4.572
D	0.026	0.036	0.660	0.914
ED	0.045	0.055	1.143	1.397
Es	0.018	0.026	0.457	0.660
F	0.051	0.051 REF		REF
G	0.100	BSC	2.540 BSC	
Н	0.539	0.579	13.691	14.707
J	0.125	MAX	3.175 MAX	
K	0.050	REF	1.270 REF	
L	0.000	0.010	0.000	0.254
M	0.088	0.102	2.235	2.591
N	0.018	0.026	0.457	0.660
P	0.058	0.078	1.473	1.981
R	0°	8°	0°	8°
S	0.116	REF	2.946	REF
U	0.200	MIN	5.080 MIN	
V	0.250 MIN		6.350 MIN	

GENERIC MARKING DIAGRAM*



XXXXXX = Specific Device Code

= Assembly Location

= Wafer Lot 1 Υ = Year ww = Work Week G = Pb-Free Package

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16.155		. ———	- 8.380
16.155			2X 3.504

SOLDERING FOOTPRINT*

← 10.490 →

	ļ [2X 3.504
2X	(1.016 →		Ī	<u> </u>
		5.080 PITCH	DIME	NSIONS: MILLI

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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^{*}This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$

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